THYRISTOR BEHAVIOR AT CRYOGENIC TEMPERATURES R.Trendler and R.Winje 30 July 1975

ABSTRACT

Several types of thyristors have been dynamically tested at temperatures ranging from 293°K to 4.2°K to determine an effective lower temperature limit of operation. The types of thyristors tested, experimental apparatus, and test results are presented. INTRODUCTION

As superconducting systems become more prevalent, the like-lihood of semiconductor operation at cryogenic temperatures is increased. To study one aspect of this, several thyristors were chosen for examination. Because of dewar space limitations four thyristors were chosen from those in use at Fermilab. Two "hockey puck" types; Westinghouse T920, Westinghouse T72C, and two stud mount types; International Rectifier 71RA, General Electric C185B, were selected. The significant parameters of these devices are listed in Table I. The thyristors were appropriately clamped or fastened to heat sinks, instrumented with thermocouples and germanium resistors, thermometers and dynamically tested with a Tektronix 576 curve tracer. Six temperatures were used in the test including room temperature tests at various times between cold tests.

EXPERIMENT

The total test fell into three individual tests; 1) 77°K liquid nitrogen immersion test; 2) 4.2°K liquid helium immersion test; and 3) (a 20°K, 30°K, 50°K) helium vapor test.

In test 1), the devices were merely immersed in liquid nitrogen and tested; in test 2), the devices were placed in a dewar and then cooled by introducing liquid helium into the dewar. The devices in both tests were cooled quite rapidly. In test 3), a thermally insulated region containing the thyristors, heatsinks, thermocouples, germanium resistors, and heating resistors was placed in a dewar. The helium transfer line was extended so as to introduce liquid helium below the isolated region. All test leads were brought out through the header assembly. By controlling a current through the header resistors the temperature of the region could be roughly controlled; i.e., ±2°K.

TESTS

The thyristor parameters which were studied included; 1) gate sensitivity, 2) gate voltage and currents, and 3) forward and reverse blocking voltages and the forward voltage anode to cathode voltage drop.

RESULTS

The detailed test results are shown in Table II.

From room temperature to 50°K the thyristors did not fail and only suffered a small loss of their rated room temperature blocking voltages. The gate current required for conduction was lower than that at room temperature in three of the devices and showed a small unexplained increase in the Westinghouse T72C.

After the devices were tested at 77°K, they were retested at room temperature. The device identified as the Westinghouse WT920 (#1) failed in that its forward and reverse blocking voltages capability was depleted. Subsequently, the device case was opened. A careful visual examination showed numerous small cracks and voids in the varnish used to seal the tapered edge of the fusion. The failure of the varnish caused the degradation in the blocking voltages. This problem could undoubtedly be solved by using a sealing material which retains more of its room temperature pliability.

Testing at temperatures of 30°K and below demonstrated that the thyristors could not be gated with the twenty volt or two ampere gate drive which was available in the test set. In most cases, the forward and reverse blocking voltage capability was degraded, but with the exception of the WT920, all the thyristors recovered this capability after they were warmed to room temperature.

The IR71RA was thermally shocked to 77°K from 293°K with no apparent degradation in its characteristics. This test was repeated ten times.

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TABLE I

PARAMETER	W920T	WT72C	IR71RA	GEC185B
Repetitive Peak off State Voltage	1200V	1800V	1400V	200V
Repetitive Peak Reverse Voltage	1200V	1800V	1400V	200V
Non-Repetitive Peak Reverse Voltage	1300V	2150V	1650V	300V
RMS on State Current	1000A	700A	110A	235A
Average Current			70A	
Peak One Cycle Surge I	16000A	7500A	1600A	3500A
di/dt	800A/μs	600A/μs	300A/µs	100A/μs
đv/đt (min)	200V/μs	300V/µs	200V/μs	200V/µs
I _H Holding Current (non)			500 ma	500 ma
DC Gate Trigger Current-40°C			35 ma	500 ma
+125°C		150 ma	•	250 ma
I _J =25C	200 ma			
DC Gate Trigger Voltage	3V	3V	3V	3V

TABLE II

LOW TEMPERATURE THYRISTOR TEST RESULTS

					6/3	6/3	6/10	6/10	6/10	6/10	6/11	
DEVICE	PARA- METER	293°K	77°K	293°K	4.2°K	293°K	293°K	20°K	30°K	50°K	293°K	- DVIE
WI72C	BVF BVR	>1700 >1700	1560 1660	>1700 >1700	70 550	Failed						BVF
#1	IGT VGT VT	15na 0.45 0_85	22 1.15 _1_3	15 0.48 0-85	NF NF 	141200						BVR
WI72C	BVF	4-0		وم هدال الأدب الأصد			>1680	500		400	>1700	7
#2	BVR IGT VGT						>1680 230 0.82	100 NF NF	NF NF	350 6 1.6	>1700 205 0.78	IGT
	V <u>r</u>				····		0.82	12		1.5	0.8	
WT920	BVF BVR	1440 950	1100 700	Failed								VGT
#1	IGT VGT VT	90 0.7 1.2	33.5 1.9 1.3	tarrea								VT
WT920	BVF BVR			1160 1300	11 1120	Failed			 	×		
#2	IGT VGT VT			88 1.54 1.0	NF NF 7	ralled						NF
WT920	BVF		 -				1500	200			200	
#3	BVR IGT						1500 104	1140 NF	NF	0.2	1500 92	
" -	VGT VT						1.64	NF 6	NF	4.5 1.2	1.6	
IR71RA	BVF	1500	1200	1500	170	1500				ينا بار بورس به مه ۱۱۷ گ		7
#1	BVR IGT VGT VT	0.5	1350 *8.75 1.75 1.3	>1500 48 0.8 0.8	1400 NF NF 20	>1500 49 0.9 1.0	Failed					
IR71RA	BVF						1540	600			1530	
#2	BVR IGT VGT VT						1680 72 0.7 0.9	600 NF NF 16	NF NF	96 20 1.6	1620 84 1.0 0.96	
GEC185B	BVF BVR IGT VGT VT	400 650 54 1.0 1.2	300 600 7.5 1.9	400 650 65 1.0	100 370 NF NF 20	400 650 68 1.4 1.1	400 650 63 1.3 1.08	350 700 63 NF 16	NF NF	NF NF	400 650 63 1.3 1.08	

BVF = forward avalanche voltage at 1 ma base open

BVR = Reverse avalanche voltage at 1 ma base open

IGT = Gate current to fire with 6 volts anode to cathode (

VGT = Gate voltage to fire with 6 volts anode to cathode

VT = Forward voltage
when fired for
500 ma ≤I_T≤ 250 ma
where I_T = forward
current

WF = No fire